

Title

Effect of halogen ions on low thermal conductivity of cesium halide perovskite

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Abstract

The lattice dynamics of CsSnX_3 ($X = \text{Cl}, \text{Br}, \text{and I}$) and CsPbI_3 , which are low thermal conductivity materials, are investigated using first-principles phonon calculations. Because of the strong lattice anharmonicity and accompanying instability of high-temperature cubic phases, the self-consistent phonon theory, which can incorporate the effect of lattice anharmonicity at a mean-field level, is applied in this study. The calculated lattice thermal conductivity reproduced a low thermal conductivity, as shown experimentally, owing to the short phonon lifetime due to the incoherent scattering contribution of Cs atoms. The halogen ion dependence on thermal conductivity reveals that CsSnCl_3 exhibits an anomalous lattice thermal conductivity that is as low as that of CsSnBr_3 . This indicates that the lattice dynamics cannot be explained merely in terms of the atomic mass of the compounds. The low thermal conductivity of CsSnCl_3 is caused by the exceptionally short phonon lifetime; further, a bonding analysis suggests that covalent bonding contributes significantly to the unusual anharmonicity of CsSnCl_3 .

1. Introduction

The efficiency of a thermoelectric material can be estimated by a dimensionless figure of merit ZT , which is defined as $S^2\sigma T/\kappa$, where S is the Seebeck coefficient, σ is the electrical conductivity, T is the temperature, and κ is the thermal conductivity¹. For a better conversion efficiency, the Seebeck coefficient and electrical conductivity must be increased, whereas the thermal conductivity must be reduced. Previous studies indicate that the formation of grain boundaries and interfaces in thermoelectric materials enhances phonon scattering, resulting in desirable thermal conductivities²⁻⁴. In addition, lattice thermal conductivity decreases with the increase in phonon scattering due to the rattling motion of embedded atoms. This mechanism is well known in clathrate or skutterudite compounds and has been suggested for cesium halide perovskite systems⁵.

The general chemical formula of halide perovskites is ABX_3 , where A represents organic molecule CH_3NH_3 or inorganic atom Cs, B represents Pb or Sn, and X represents halogen (I, Br, Cl) atoms⁵⁻⁸. These halide perovskites have been studied extensively as light absorbers for solar cells⁹⁻¹¹. Pisoni *et al.* reported that $CH_3NH_3PbI_3$ has a low thermal conductivity (0.3–0.5 W/mK at 300 K)¹². This thermal property suggests the potential of halide perovskites as a thermoelectric material. Furthermore, Lee *et al.*⁵ reported the low lattice thermal conductivities of all-inorganic halide perovskites $CsSnI_3$ (orthorhombic), $CsPbBr_3$ (orthorhombic), and $CsPbI_3$ (yellow polymorph), which were 0.38, 0.42, and 0.45 W/mK at room temperature, respectively. These studies indicate that all-inorganic halide perovskites have ultralow lattice thermal conductivities.

Materials that have low thermal conductivities are expected to exhibit unique and interesting lattice dynamics. Except for the rattling mechanism, Hata *et al.* presented the mechanism contributing to the low thermal transport properties of $CH_3NH_3PbI_3$ ¹³. They discovered that a decreasing thermal conductivity is mainly derived from the rotation motion of CH_3NH_3 molecules. Furthermore, Shulumba *et al.* reported the unusual low thermal conductivity of PbSe due to its unusual thermal conductivity arising from its intrinsic localized mode that halts thermal transport¹⁴. The intrinsic localized mode of PbSe is confirmed by neutron scattering measurements¹⁵. Rattling motions or the intrinsic localization mode are interesting and important for thermal transport as they reveal the details of phonon properties through calculations. In this regard, first-principles calculations are crucial for investigating the phonon properties of halide perovskites, regardless of whether

rattling motions and other contributions affect the lattice thermal conductivity.

However, in these low-lattice thermal conductivity materials, the phonon lifetime is reduced owing to phonon–phonon scattering, and this strong lattice anharmonicity leads to breakdown of simple picture, which approximates lattice vibration as a harmonic oscillator. Furthermore, halide perovskites are known to undergo a transition from the orthorhombic to tetragonal to cubic phase as a function of temperature^{6, 16}. Although the lattice thermal conductivity of the cubic phase was evaluated by first-principles phonon calculation⁷, their lattice thermal conductivity was affected by the phonon soft modes. Such dynamical instability has also been reported in a previous phonon study¹⁷. Hence, to estimate the lattice thermal conductivity of the high-temperature phase, self-consistent phonon (SCPH) theory is an appropriate approach, which includes lattice anharmonicity and enables us to calculate the accurate phonon frequency at a finite temperature. This approach was successfully employed for cubic SrTiO₃ perovskite, which is of a high-temperature phase¹⁸. Patrick *et al.* reported the phonon dispersion of cubic CsSnI₃ at 500 K using SCPH theory¹⁹. Furthermore, using SCPH theory, the lattice thermal conductivity of cubic perovskites can be calculated.

Herein, we report the lattice dynamics of all-inorganic halide perovskites of cubic CsSnX₃ (X = Cl, Br, and I) and CsPbI₃ using SCPH theory. SCPH theory successfully reproduces the phonon dispersion of the finite temperature, which is consistent with a previous study¹⁹. The lattice thermal conductivity of cubic phases based on the Boltzmann transport equation within the relaxation time approximation shows the unusual lattice thermal conductivity of CsSnCl₃. This is related to the short phonon lifetime caused by the difference in covalent bonding. This study is the first to provide the thermal properties of cubic all-inorganic halide perovskites CsSnX₃ (X = Cl, Br, and I) and CsPbI₃ based on first-principles calculations.

2. Calculation procedure

We performed first-principles phonon calculations for cubic CsSnX₃ (X = Cl, Br, and I) and CsPbI₃ using the self-consistent phonon approach implemented in the ALAMODE code^{18, 20} with VASP code²¹⁻²². The simplest approximation in lattice dynamics theory is harmonic approximation. By considering the potential energy V between two atoms, we can express energy as a Taylor expansion with respect to atomic displacements from equilibrium positions at zero temperature:

$$\begin{aligned} V - V_0 &= V_2 + V_3 + V_4 + \dots \\ &= \frac{1}{2!} \sum_{i,j} \Phi_{i,j} u_i u_j + \frac{1}{3!} \sum_{i,j,k} \Phi_{i,j,k} u_i u_j u_k + \frac{1}{4!} \sum_{i,j,k,l} \Phi_{i,j,k,l} u_i u_j u_k u_l + \dots, \end{aligned} \quad (1)$$

where V_n is the potential energy of the n th-order contribution, Φ is the force constant, and u is the atomic displacement with the index of atoms i, j, k , and l . The harmonic approximation involves neglecting all terms of power higher than two. The harmonic approximation provides many features, such as a link between vibrational frequencies, wave vectors, and interatomic forces, and applications in areas such as the thermodynamic properties of materials. Meanwhile, several physical properties, such as thermal expansion and thermal conductivity, and behaviors such as phase transitions, are not explained by the harmonic model. These properties originate from lattice anharmonicity and can be treated theoretically by including higher-order terms.

The second- and fourth-order force constants should be extracted to calculate the phonon dispersion, including the anharmonic effect with SCPH theory¹⁸. The anharmonic phonon frequency Ω is defined as follows:

$$\Omega_q^2 = \omega_q^2 + 2\Omega_q I_q, \quad (2)$$

where ω_q is the harmonic phonon frequency calculated by second-order force constants, and I_q is the anharmonic phonon self-energy calculated by fourth-order force constants. First, we calculated the phonon dispersion only with second-order force constants. Next, by solving this equation self-consistently, we can obtain the anharmonic frequency Ω_q .

The third-order force constant is necessitated to evaluate the lattice thermal conductivity. In the Boltzmann transport equation within the relaxation time approximation, the lattice conductivity is expressed as the product of the specific heat c , phonon group velocity v , and lifetime τ . Here, the lattice thermal conductivity κ_{ph} is expressed as follows:

$$\kappa_{\text{ph}} = \frac{1}{NV} \sum_q c_q v_q^2 \tau_q, \quad (3)$$

where N is the number of q points in the Brillouin zone, and V is the volume of the cell. The specific heat and phonon group velocity can be calculated from the phonon dispersion. The phonon lifetime is calculated by the phonon scattering probability, which is derived from the third-order force constant. Therefore, we calculated the second-, third-, and fourth-order force constants from first-principles calculations. In this study, the fourth-order force constants were determined with fifth-nearest neighbor shells, whereas fifth- and sixth-order force constants were considered for fifth-nearest neighbor pairs. These force constants were extracted from displacement–force datasets using the linear regression implemented in ALAMODE. We examined two displacement–force datasets. One is the finite displacement (FD) dataset²³⁻²⁴, another is the first-principles molecular dynamics (FPMD) dataset²⁵⁻²⁶.

In the DFT calculation, the interaction between the ion core and valence electrons was described by the projector-augmented wave method²⁷⁻²⁸. The exchange and correlation functions were obtained using a generalized gradient approximation, as proposed by Perdew *et al.*²⁹⁻³⁰. We used a plane wave energy cutoff of 400 eV, a convergence criterion for the electronic self-consistency loop of 10^{-8} eV, a Γ -point-centered k -mesh that was limited to 0.15 \AA^{-1} , and the Gaussian smearing method with a smearing width of 0.05 eV. We calculated the Born effective charges and the dielectric tensor using density functional perturbation theory to consider the nonanalytic part of the dynamical matrix. For the finite displacement approach, we used a displacement distance of 0.01 \AA . For FPMD, we used the 2000 step results without the initial 1000 steps simulated at $T = 300 \text{ K}$ with a timestep of 1 fs. These results provided the 2000 atomic configuration for FPMD dataset, but the displacement at only $T = 300 \text{ K}$ is not suitable for calculating temperature dependence of physical properties of systems. Therefore, additional data, where random displacements by 0.1 \AA of 400 atomic

configurations equally spaced in time was added to FPMD dataset. This procedure follows previous studies^{18, 31}. In addition, the least absolute shrinkage and selection operator (LASSO) technique was employed to estimate force constants. The hyperparameter of LASSO was selected by minimizing the four-fold cross-validation score.

3. Results & discussion

First, we calculated and compared the phonon dispersion of cubic CsSnI₃ using various calculation methods. The crystal structure of the cubic phase of the calculated halide perovskite ABX_3 was categorized as $Pm\bar{3}m$ (221). The A , B , and X atoms were located at the 1a, 1b, and 3d Wyckoff positions, respectively. The lattice constants of CsSnI₃ were $a = 6.281 \text{ \AA}$, which is similar to the experimental values of $a = 6.2057 \text{ \AA}$ ³². Figure 1 shows a comparison of the phonon dispersion calculated using various calculation methods. Dotted lines represent the calculated result of the harmonic approximation with second-order force constants in Eq. (1). The wave vectors of the phonon dispersion are shown along the high-symmetry points, Γ (0, 0, 0) - X (0.5, 0, 0) - M (0.5, 0.5, 0) - Γ (0, 0, 0) - R (0.5, 0.5, 0.5) - M (0.5, 0.5, 0). In this dispersion curve, a negative frequency was observed at the M and R points, which means that cubic CsSnI₃ is dynamically unstable at $T = 0$. This result is consistent with those of the previous studies^{7, 17, 19}.

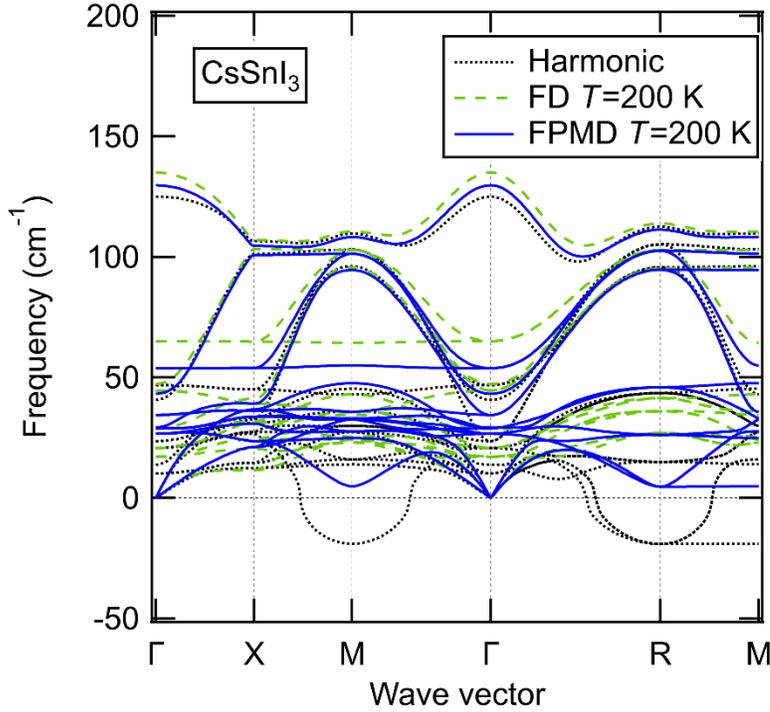


Fig. 1 Phonon dispersion of cubic CsSnI_3 calculated using harmonic approximations (dotted lines) and SCPH theory at 200 K. Solid and dashed lines show results with force constants extracted using FPMD and FD methods, respectively.

For the high-temperature stable phase, the SCPH calculation enables us to obtain the phonon dispersion at a finite temperature by incorporating both the fourth- and second-order force constants. The solid and dashed lines show the results of the SCPH calculation. We analyzed three datasets to extract the fourth-order force constants: the FPMD with/without random displacements and FD datasets. For the FPMD dataset, the calculation converged at $140 \text{ K} < T < 1000 \text{ K}$, where the convergence criteria included the positive phonon frequency. Convergence at a finite temperature in the SCPH calculation is a reasonable result in terms of lattice dynamics. Difference of the result between with and without the random displacement was quite small, hence the result of FPMD dataset with the random displacements is shown in this paper. However, for the FD dataset, the calculation converged at $0 < T < 220 \text{ K}$, which is rather unusual. The dispersion curves obtained were

compared at 200 K, where both SCPH calculations converged. A significant difference was observed at points M and R. The cubic phase was experimentally reported as a stable phase above 440 K⁶. The result of the FPMD dataset, which was reproduced as a high-temperature stable phase, was consistent with experimental observations. Previous calculations indicated the phonon dispersion of cubic CsSnI₃ at 500 K¹⁹, which is similar to our FPMD dataset dispersion at 500 K. In FD approach, we speculated that the displacement is too small to extract the high-order force constant, which is smaller effect than second- and third-order term. Therefore, the FPMD dataset with random displacement is preferred for extracting the fourth-order force constant in this study.

Figure 2 shows the phonon dispersions of CsSnCl₃, CsSnBr₃, and CsPbI₃ using SCPH theory at 300 K, which are compared with the result of harmonic approximation. The lattice constants of CsSnX₃ (X = Cl, and Br) and CsPbI₃ were $a = 5.631$, 5.895 , and 6.395 Å, respectively, which were consistent with the experimental values (CsSnCl₃ $a = 5.5734$ Å; CsSnBr₃ $a = 5.791$ Å; CsPbI₃ $a = 6.2894$ Å)³². Solid and dotted lines show the results of SCPH theory at 300 K and harmonic approximation, respectively. Each halide perovskite contained no imaginary phonon mode owing to SCPH theory.

For the calculation temperature range $0 < T < 1000$ K at every 10 K step, self-consistent calculations converged at 80–1000 K for CsSnCl₃, 100–1000 K for CsSnBr₃, and 220–1000 K for CsPbI₃, indicating the absence of imaginary frequency and the stability for these temperature ranges. These results are consistent with the experimental observation, i.e., the cubic phase is a high-temperature phase. The experimental phase transition temperatures of the cubic phases of CsSnCl₃, CsSnBr₃, CsSnI₃, and CsPbI₃ were $T = 293$, 286 , 440.5 , and 634 K, respectively,^{6, 33-35}. For the phase transition temperature, taking account of only fourth-order contribution for temperature dependence of phonon frequency was not enough for comparison with experimental values. We need to include the frequency shift or the thermal expansion effect from third-order anharmonic contribution. Furthermore, experimental observation suggested that the phase transitions in CsPbI₃ is not simple second-order phase transition[34].

The phonon dispersion of CsPbI₃ was distributed at lower frequencies compared with those of other perovskites. The distribution of phonon frequencies was simply understood in terms of the atomic mass of the compounds. The phonon dispersion and density of states indicated that the phonon frequency decreased with increasing atomic mass. Hence,

we can expect a low group velocity v ($v_q = \frac{\partial \omega_q}{\partial q}$) for a heavy atomic mass system.

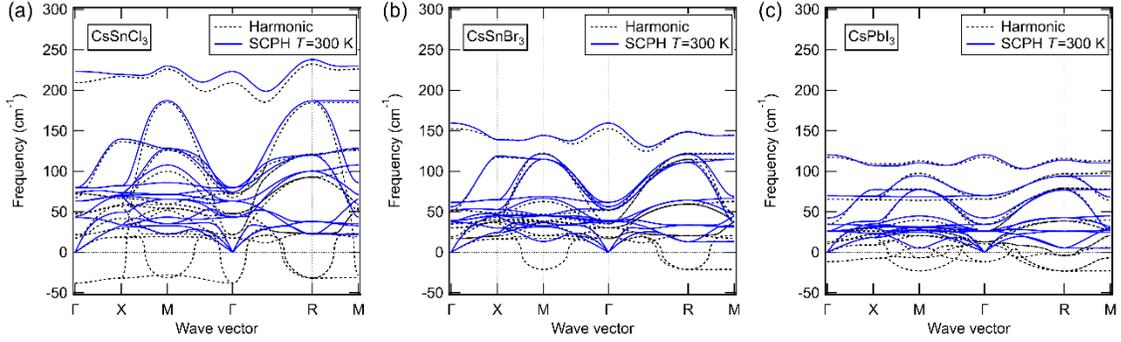


Fig. 2 Phonon dispersion of (a) CsSnCl₃, (b) CsSnBr₃, and (c) CsPbI₃. Solid lines show phonon dispersion at 300 K using SCPH method. Dotted lines show phonon dispersion within harmonic approximation.

The lattice thermal conductivity was calculated from the obtained phonon dispersions with no imaginary frequency. Figure 3 shows the lattice thermal conductivity of CsSnX₃ (X = Cl, Br, and I) and CsPbI₃. It is noteworthy that our calculations demonstrated the low lattice thermal conductivity in these halide perovskites. CsPbI₃ showed the lowest lattice thermal conductivity. This can be understood from the heavy atomic mass of Pb; a system with heavy atoms has a low group velocity owing to the low phonon frequency. Therefore, the highest lattice thermal conductivity of CsSnCl₃ was expected because of the lightweightness of Cl; however, the thermal conductivity of CsSnCl₃ is similar to that of CsSnBr₃. Compared with other Sn-based perovskites, the low lattice thermal conductivity of CsSnCl₃ appears unusual.

In a previous study⁵, the lattice thermal conductivities of nano single crystals of CsSnI₃ (orthorhombic), CsPbBr₃ (orthorhombic), and CsPbI₃ (yellow polymorph) were reported to be $\kappa_{\text{ph}} = 0.38, 0.42, \text{ and } 0.45 \text{ W/mK}$ at room temperature, respectively. Therefore, the halide perovskites indicated lower thermal conductivities than the calculated values. The difference between the calculated and experimental values may be due to the following reasons: (1) difference in crystal structure; (2) lattice imperfection not included in the calculation; (3) thermal expansion and high-order anharmonicity not included in the

calculation. We may be able to estimate the effect of thermal expansion and high-order anharmonicity; however, we would require the experimental data of high-quality bulk single crystals of cubic all-inorganic halide perovskites to disregard the effects of (1) and (2).

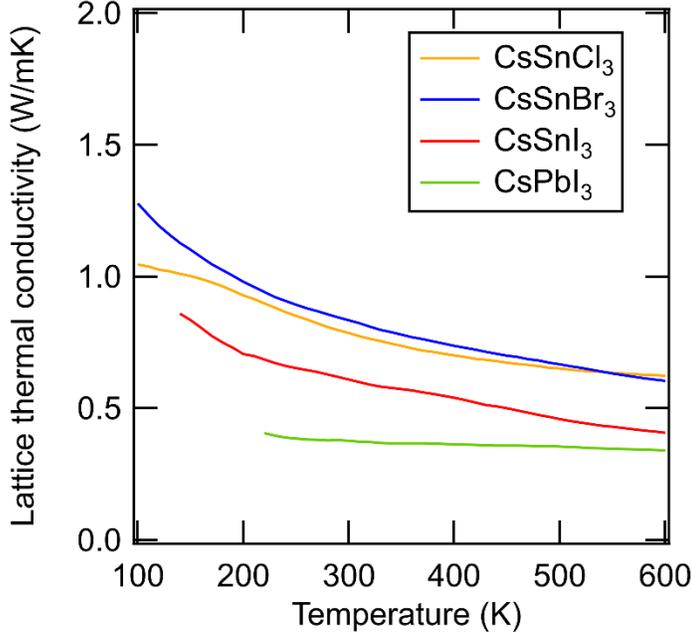


Fig. 3 Temperature dependence of lattice thermal conductivity of CsSnX₃ (X = Cl, Br, and I) and CsPbI₃.

The lattice thermal conductivity of CsSnCl₃ was low because the lattice thermal conductivity was proportional to the product of the specific heat, group velocity, and phonon lifetime. Figure 4(a) shows the frequency dependence of the group velocity at $T = 300$ K. The order of the group velocity was CsPbI₃ < CsSnI₃ < CsSnBr₃ < CsSnCl₃, which is clearly related to the order of atomic mass of the compounds. In CsSnCl₃, a high group velocity was observed in the frequency range of $f = 100\text{--}200$ cm⁻¹. Figure 4(b) shows the frequency dependence of the phonon lifetime at 300 K. We discovered that CsSnCl₃ exhibited a short phonon lifetime. The lifetime was shorter than that of the other perovskites above $f = 100$ cm⁻¹. The phonon lifetimes of CsPbI₃, CsSnI₃, and CsSnBr₃ indicate no clear differences, such as in the CsSnCl₃ case. Therefore, the phonon group velocity and lifetime indicate that CsSnCl₃ has a higher group velocity and shorter lifetime than the other perovskites.

In this study, the CsPbI₃ results were compared with those of previous neutron

scattering measurements for $\text{CH}_3\text{NH}_3\text{PbI}_3$ ³⁶. The phonon group velocity and lifetime of acoustic phonons in the experiment were reported to be $v = 2400$ or 1200 m/s and $\tau = 1\text{--}20$ ps, respectively. Our data indicated $v < 3000$ m/s and $\tau \approx 1\text{--}40$ ps for lower frequencies, which are similar to the results of the abovementioned experimental study, although the A site differed. Therefore, these phonon properties have been well described in our calculations. Additionally, we compared our phonon lifetimes with those of other materials. Our calculated lifetimes were one order of magnitude shorter than that of Si ³⁷, two orders of magnitude shorter than those of GaAs and CdTe ³⁸, and similar in magnitude to those of PbSe and PbTe ³⁹. From these comparisons, it was clear the phonon lifetime of the calculated halide perovskite was shorter than those of other materials.

Next, the frequency dependence of the spectrum-decomposed lattice thermal conductivities of CsSnX_3 ($X = \text{Cl}, \text{Br}, \text{and I}$) and CsPbI_3 at 300 K is shown in Fig. 4(c) to reveal the contribution of the phonon group velocity and lifetime to the lattice thermal conductivity. These spectra indicate that the lattice thermal conductivity was high around the peak frequency of the group velocity except for CsSnCl_3 . Hence, the trend of the lattice thermal conductivities of CsSnBr_3 , CsSnI_3 , and CsPbI_3 were mainly determined by the phonon group velocity. However, CsSnCl_3 indicated a low lattice thermal conductivity around the peak frequency of the group velocity owing to the short lifetime around this frequency range. This indicates that the phonon lifetime contributed significantly to the lattice thermal conductivity of CsSnCl_3 . We conclude that the low thermal conductivity of CsSnCl_3 was caused by the short phonon lifetime, which contributed more compared with the group velocity.

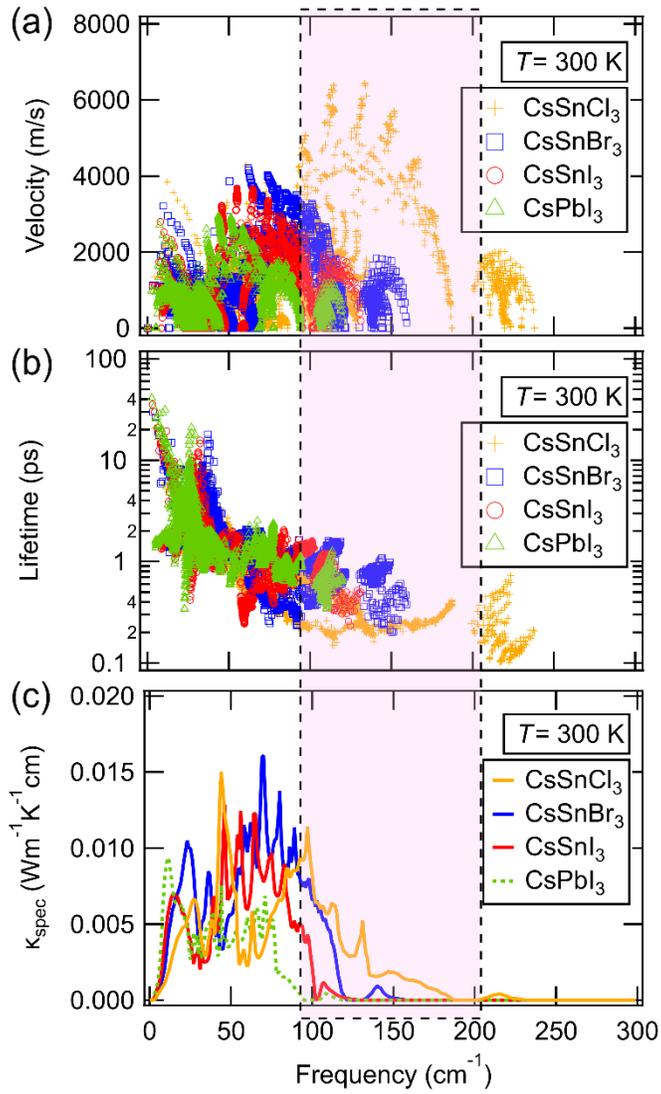


Fig. 4 Frequency dependence of (a) phonon group velocity, (b) phonon lifetime, and (c) spectrum-decomposed lattice thermal conductivity of CsSnX_3 ($X = \text{Cl}, \text{Br}, \text{and I}$) and CsPbI_3 at 300 K.

Next, we discuss the origin of the short phonon lifetime above $f = 100 \text{ cm}^{-1}$ for CsSnCl_3 . The intrinsic localized mode reported in ¹⁴ is an interesting scenario for the anomalous behavior; however, it may be rejected in CsSnCl_3 . From the phonon dispersions, as shown in Fig. 2, a flattening band was observed for all systems and not only for CsSnCl_3 . Additionally, the rattling motion of Cs atoms was analyzed ^{5-6, 18}. The atom-projected phonon densities of states of CsSnX_3 ($X = \text{Cl, Br, and I}$) and CsPbI_3 are shown in Fig. 5. The phonon density of states of Cs atoms was distributed around 30 cm^{-1} . The distribution of Sn shifted to a higher frequency with increasing light atoms. Furthermore, the X site shifted to a high frequency with such a substitution. Although the rattling motion decreased the lattice thermal conductivity, it did not contribute to the short lifetime of CsSnCl_3 because the short lifetime was mainly observed above $f = 100 \text{ cm}^{-1}$. However, Cs rattling motions causing a low thermal conductivity is expected for all Cs halide perovskite systems. Based on the phonon density of states and the dispersions, the flattening phonon mode as the intrinsic localized mode and the rattling of Cs atoms did not contribute to the unusual short lifetime of CsSnCl_3 .

Meanwhile, we discovered that the phonon contribution above $f = 100 \text{ cm}^{-1}$ mainly comprised Sn and halide ions, as shown in Fig. 5. Sn and halogen ions were covalently bonded and adjacent to each other in the perovskite structure. We speculate that this covalent bonding may generate an anisotropic motion (vibration) of ions and cause a strong lattice anharmonicity in the system. To investigate this effect on the phonon lifetime, we conducted a bonding analysis of the Sn–X bonds for CsSnX_3 . For chemical bond analysis, we calculated the projected crystal orbital Hamilton population (pCOHP) from the obtained DFT output using the local-orbital basis suite toward electronic-structure reconstruction code ⁴⁰⁻⁴³. The pCOHP indicates the orbital-pair interaction (bonding, antibonding, or nonbonding) by estimating the overlap of the orbitals, which is analyzed from the wave function.

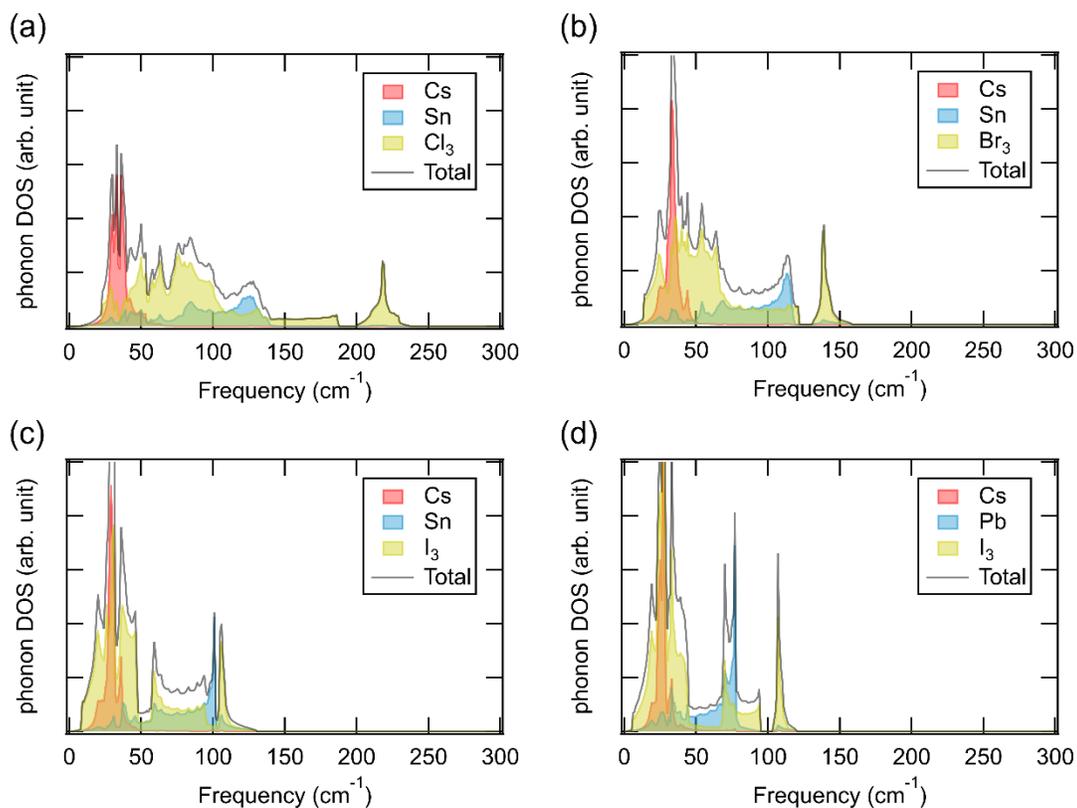


Fig. 5 Atom-projected phonon density of states of CsSnX_3 ($X = \text{Cl}, \text{Br}, \text{and I}$) and CsPbI_3 .

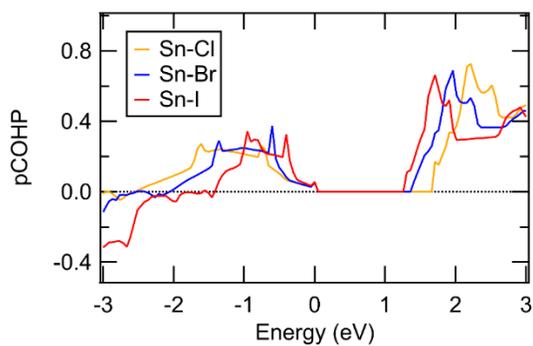


Fig. 6 Projected crystal orbital Hamilton populations of Sn-X ($X = \text{Cl}, \text{Br}, \text{I}$) bonds, where the energy is shown with respect to the Fermi energy.

Figure 6 shows the pCOHPs of Sn–X (X = Cl, Br, I) bonds, where the energy ε is shown with respect to the Fermi energy. The pCOHP indicates the antibonding contribution by a positive sign, such that the Sn–X bonds around the bandgap are antibonding contributions. This bonding interaction for Sn–I is similar to those for MASnI₃ and FASnI₃⁴⁴. We focused on the occupied region ($\varepsilon < 0$). For the X = Cl case, the population ($-2.5 < \varepsilon < 0$) was broader than that of the X = I case ($-1.5 < \varepsilon < 0$). The overlap of orbitals between Sn–Cl and Sn–I bonding differed. A broad pCOHP in CsSnCl₃ implies a large transfer integral between the Sn and Cl orbitals; therefore, a strong covalent bond is expected in Sn–Cl bonding. This calculated result is consistent with our speculation. Whereas the pCOHP analysis presents the chemical bonding information for covalent bonding, such an overlap difference indicates the difference in covalent bonding between Sn–Cl and other pairs. Hence, we speculate that the unusual lattice anharmonicity of CsSnCl₃ was caused by the difference in covalent bonding.

4. Conclusion

We investigated the lattice dynamics and lattice thermal conductivity of the cubic phases of CsSnX_3 ($X = \text{Cl, Br, and I}$) and CsPbI_3 halide perovskites using first-principles phonon calculations based on the SCPH theory. From the phonon dispersion at a finite temperature, we discovered that the cubic phase was metastable. The lattice thermal conductivity of cubic halide perovskites was calculated using the Boltzmann transport equation with a relaxation time approximation. The calculated lattice thermal conductivities of cubic halide perovskites indicated a low thermal conductivity, which was slightly larger than the experimental value at low-temperature phases. We discovered that CsSnCl_3 exhibited an anomalously low lattice thermal conductivity because of its short phonon lifetime. Our analysis indicated that Sn and Cl were contributed around the frequency range of short phonon lifetime. Based on the phonon density of states and dispersions, clear evidence of participation of the rattling motion or the flattening phonon mode did not observed as the origin of the unusual short lifetime. Instead, we speculated based on bonding analysis that the unusual anharmonicity of CsSnCl_3 was caused by the difference in covalent bonding. Present calculation techniques are useful for obtaining the thermal properties of all-inorganic halide perovskites at high-temperature phases. Our approach incorporating SCPH theory provides a new perspective on anharmonic materials.

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